5.0 V ECL 1:2 Differential Fanout Buffer

The MC10EL/100EL11 is a differential 1:2 fanout buffer. The device is functionally similar to the E111 device but with higher performance capabilities. The within-device skew and propagation delay is significantly improved over the E111.

The differential inputs of the EL11 employ clamping circuitry to maintain stability under open input conditions. If the inputs are left open (pulled to V_{EE}) the Q outputs will go LOW.

The 100 Series contains temperature compensation.

Features

- 265 ps Propagation Delay
- 5 ps Skew Between Outputs
- PECL Mode Operating Range: $V_{CC} = 4.2$ V to 5.7 with $V_{EE} = 0$ V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -4.2 V to -5.7 V
- Internal Input Pulldown Resistors
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

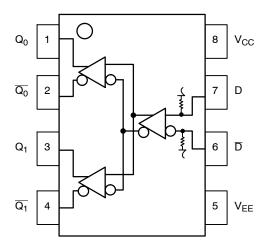
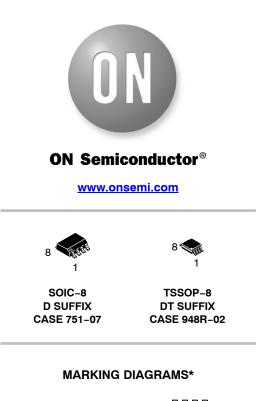
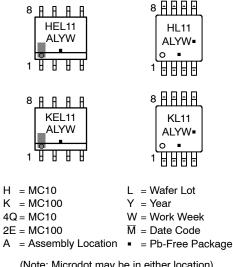


Figure 1. Logic Diagram and Pinout Assignment

Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
|------------------------------|------------------|
| D, D | ECL Data Inputs |
| Q0, <u>Q0;</u> Q1, <u>Q1</u> | ECL Data Outputs |
| V _{CC} | Positive Supply |
| V _{EE} | Negative Supply |





(Note: Microdot may be in either location) *For additional marking information, refer to Application Note <u>AND8002/D</u>.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

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Table 2. ATTRIBUTES

| Characteristics | Value |
|---|----------------------|
| Internal Input Pulldown Resistor | 75 KΩ |
| Internal Input Pullup Resistor | N/A |
| ESD Protection Human Body Model Machine Model | > 1 KV > 100 V |
| Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1) | Pb-Free Pkg |
| SOIC-8 TSSOP-8 | Level 1 Level 3 |
| Flammability Rating Oxygen Index: 28 to 34 | UL 94 V–0 @ 0.125 in |
| Transistor Count | 44 |
| Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test | |

1. For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
|----------------------|--|--|---|---------------|------|
| V _{CC} | PECL Mode Power Supply | V _{EE} = 0 V | | 8 | V |
| V_{EE} | NECL Mode Power Supply | $V_{CC} = 0 V$ | | -8 | V |
| VI | PECL Mode Input Voltage NECL Mode Input Voltage | V _{EE} = 0 V V _{CC} = 0 V | $\begin{array}{l} V_I \leq V_{CC} \\ V_I \geq V_{EE} \end{array}$ | 6 -6 | V |
| I _{out} | Output Current | Continuous Surge | | 50 100 | mA |
| T _A | Operating Temperature Range | | | -40 to +85 | °C |
| T _{stg} | Storage Temperature Range | | | -65 to +150 | °C |
| θ_{JA} | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | SOIC-8 | 190 130 | °C/W |
| θ_{JC} | Thermal Resistance (Junction-to-Case) | Standard Board | SOIC-8 | 41 to 44 | °C/W |
| θ_{JA} | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | TSSOP-8 | 185 140 | °C/W |
| θ_{JC} | Thermal Resistance (Junction-to-Case) | Standard Board | TSSOP-8 | 41 to 44 ± 5% | °C/W |
| T _{sol} | Wave Solder (Pb-Free) | <2 to 3 sec @ 260°C | | 265 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. JEDEC standard multilayer board – 2S2P (2 signal, 2 power)

Table 4. 10EL SERIES PECL DC CHARACTERISTICS (V_{CC} = 5.0 V; V_{EE} = 0.0 V (Note 1))

| | | | -40°C | | | 25°C | | | 85°C | | |
|-----------------|---|------|-------|------|------|------|------|------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current | | 26 | 31 | | 26 | 31 | | 26 | 31 | mA |
| V _{OH} | Output HIGH Voltage (Note 2) | 3920 | 4010 | 4110 | 4020 | 4105 | 4190 | 4090 | 4185 | 4280 | mV |
| V _{OL} | Output LOW Voltage (Note 2) | 3050 | 3200 | 3350 | 3050 | 3210 | 3370 | 3050 | 3227 | 3405 | mV |
| V _{IH} | Input HIGH Voltage (Single-Ended) | 3770 | | 4110 | 3870 | | 4190 | 3940 | | 4280 | mV |
| V _{IL} | Input LOW Voltage (Single-Ended) | 3050 | | 3500 | 3050 | | 3520 | 3050 | | 3555 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Differential) (Note 3) | 2.5 | | 4.6 | 2.5 | | 4.6 | 2.5 | | 4.6 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| Ι _{ΙL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.3 | | | μΑ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.25 V / –0.5 V.

Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V. 2.

3. VIHCMR min varies 1:1 with VEE, VIHCMR max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between VPPmin and 1 V.

Table 5. 10EL SERIES NECL DC CHARACTERISTICS (V_{CC} = 0.0 V; V_{EE} = -5.0 V (Note 1))

| | | | -40°C | | 25°C | | 85°C | | | | |
|--------------------|---|-------|-------|-------|-------|-------|-------|-------|-------|-------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current | | 26 | 31 | | 26 | 31 | | 26 | 31 | mA |
| V _{OH} | Output HIGH Voltage (Note 2) | -1080 | -990 | -890 | -980 | -895 | -810 | -910 | -815 | -720 | mV |
| V _{OL} | Output LOW Voltage (Note 2) | -1950 | -1800 | -1650 | -1950 | -1790 | -1630 | -1950 | -1773 | -1595 | mV |
| V _{IH} | Input HIGH Voltage (Single-Ended) | -1230 | | -890 | -1130 | | -810 | -1060 | | -720 | mV |
| VIL | Input LOW Voltage (Single-Ended) | -1950 | | -1500 | -1950 | | -1480 | -1950 | | -1445 | mV |
| V _{IHCMR} | Input HIGH Voltage Common Mode Range (Differential) (Note 3) | -2.5 | | -0.4 | -2.5 | | -0.4 | -2.5 | | -0.4 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| ۱ _{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.3 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.25 V / -0.5 V. 2. Outputs are terminated through a 50 Ω resistor to V_{CC} - 2.0 V.

3. VIHCMR min varies 1:1 with VEE, VIHCMR max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between VPPmin and 1 V.

Table 6. 100EL SERIES PECL DC CHARACTERISTICS (V_{CC} = 5.0 V; V_{EE} = 0.0 V (Note 1))

| | | | −40°C | | | 25°C | | | 85°C | | |
|-----------------|---|------|--------------|------|------|------|------|------|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current | | 26 | 31 | | 26 | 31 | | 30 | 36 | mA |
| V _{OH} | Output HIGH Voltage (Note 2) | 3915 | 3995 | 4120 | 3975 | 4045 | 4120 | 3975 | 4050 | 4120 | mV |
| V _{OL} | Output LOW Voltage (Note 2) | 3170 | 3305 | 3445 | 3190 | 3295 | 3380 | 3190 | 3295 | 3380 | mV |
| V _{IH} | Input HIGH Voltage (Single-Ended) | 3835 | | 4120 | 3835 | | 4120 | 3835 | | 4120 | mV |
| V _{IL} | Input LOW Voltage (Single-Ended) | 3190 | | 3525 | 3190 | | 3525 | 3190 | | 3525 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Differential) (Note 3) | 2.5 | | 4.6 | 2.5 | | 4.6 | 2.5 | | 4.6 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| Ι _{ΙL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.8 V / -0.5 V.

2. Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V.

3. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP}min and 1 V.

Table 7. 100EL SERIES NECL DC CHARACTERISTICS ($V_{CC} = 0.0 \text{ V}$; $V_{EE} = -5.0 \text{ V}$ (Note 1))

| | | | –40°C | | 25°C | | 85°C | | | | |
|--------------------|---|-------|-------|-------|-------|-------|-------|-------|-------|-------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| I _{EE} | Power Supply Current | | 26 | 31 | | 26 | 31 | | 30 | 36 | mA |
| V _{OH} | Output HIGH Voltage (Note 2) | -1085 | -1005 | -880 | -1025 | -955 | -880 | -1025 | -955 | -880 | mV |
| V _{OL} | Output LOW Voltage (Note 2) | -1830 | -1695 | -1555 | -1810 | -1705 | -1620 | -1810 | -1705 | -1620 | mV |
| VIH | Input HIGH Voltage (Single-Ended) | -1165 | | -880 | -1165 | | -880 | -1165 | | -880 | mV |
| VIL | Input LOW Voltage (Single-Ended) | -1810 | | -1475 | -1810 | | -1475 | -1810 | | -1475 | mV |
| V _{IHCMR} | Input HIGH Voltage Common Mode Range (Differential) (Note 3) | -2.5 | | -0.4 | -2.5 | | -0.4 | -2.5 | | -0.4 | V |
| I _{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| IIL | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.8 V / -0.5 V.

2. Outputs are terminated through a 50 Ω resistor to V_{CC} – 2.0 V.

 V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP}min and 1 V.

| | | | -40°C | | 25°C | | 85°C | | | | |
|--------------------------------------|---|-----|-------|------|------|-----|------|-----|------|------|------|
| Symbol | Characteristic | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| fmax | Maximum Toggle Frequency | | | | | 1.5 | | | | | GHz |
| t _{PLH} t _{PHL} | Propagation Delay to Output | 135 | 260 | 385 | 190 | 265 | 340 | 215 | 29*0 | 365 | ps |
| t _{SKEW} | Within-Device Skew (Note 2) Duty Cycle Skew (Note 3) | | 5 | | | 5 | 20 | | 5 | 20 | ps |
| t JITTER | Random Clock Jitter (RMS) | | | | | 0.6 | | | | | ps |
| V _{PP} | Input Swing (Note 4) | 150 | | 1000 | 150 | | 1000 | 150 | | 1000 | mV |
| t _r t _f | Output Rise/Fall Times Q (20% – 80%) | 100 | 225 | 350 | 100 | 225 | 350 | 100 | 225 | 350 | ps |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. 10 Series: V_{EE} can vary +0.25 V / –0.5 V.

100 Series: $\overline{V_{EE}}$ can vary +0.8 V / -0.5 V.

2. Within-device skew defined as identical transitions on similar paths through a device.

3. Duty cycle skew is the difference between a t_{PLH} and t_{PHL} propagation delay through a device.

4. V_{PP}(min) is minimum input swing for which AC parameters guaranteed. The device has a DC gain of ≈ 40.

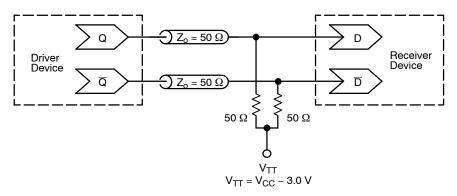


Figure 2. Typical Termination for Output Driver and Device Evaluation (See Application Note <u>AND8020/D</u> – Termination of ECL Logic Devices.)

ORDERING INFORMATION

| Device | Package | Shipping [†] | | | | |
|----------------|----------------------|-----------------------|--|--|--|--|
| MC10EL11DG | SOIC-8 (Pb-Free) | 98 Units / Rail | | | | |
| MC10EL11DR2G | SOIC-8 (Pb-Free) | 2500 / Tape & Reel | | | | |
| MC10EL11DTG | TSSOP-8 (Pb-Free) | 100 Units / Rail | | | | |
| MC100EL11DG | SOIC-8 (Pb-Free) | 98 Units / Rail | | | | |
| MC100EL11DR2G | SOIC-8 (Pb-Free) | 2500 / Tape & Reel | | | | |
| MC100EL11DTG | TSSOP-8 (Pb-Free) | 100 Units / Rail | | | | |
| MC100EL11DTR2G | TSSOP-8 (Pb-Free) | 2500 / Tape & Reel | | | | |

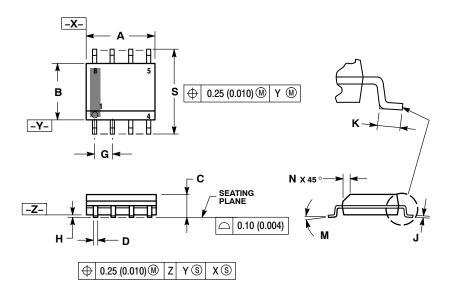
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

Resource Reference of Application Notes

| AN1405/D | - | ECL Clock Distribution Techniques |
|-----------|---|---|
| AN1406/D | - | Designing with PECL (ECL at +5.0 V) |
| AN1503/D | - | ECLinPS [™] I/O SPiCE Modeling Kit |
| AN1504/D | - | Metastability and the ECLinPS Family |
| AN1568/D | - | Interfacing Between LVDS and ECL |
| AN1672/D | - | The ECL Translator Guide |
| AND8001/D | - | Odd Number Counters Design |
| AND8002/D | - | Marking and Date Codes |
| AND8020/D | - | Termination of ECL Logic Devices |
| AND8066/D | - | Interfacing with ECLinPS |
| AND8090/D | - | AC Characteristics of ECL Devices |

PACKAGE DIMENSIONS

SOIC-8 NB CASE 751-07 **ISSUE AK**

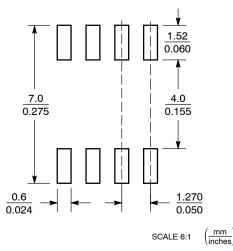


NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.
- STANDARD IS 751-07.

| | MILLIN | IETERS | INC | HES | | |
|-----|--------|--------|-----------|-------|--|--|
| DIM | MIN | MAX | MIN | MAX | | |
| Α | 4.80 | 5.00 | 0.189 | 0.197 | | |
| В | 3.80 | 4.00 | 0.150 | 0.157 | | |
| С | 1.35 | 1.75 | 0.053 | 0.069 | | |
| D | 0.33 | 0.51 | 0.013 | 0.020 | | |
| G | 1.27 | 7 BSC | 0.050 BSC | | | |
| Н | 0.10 | 0.25 | 0.004 | 0.010 | | |
| ſ | 0.19 | 0.25 | 0.007 | 0.010 | | |
| К | 0.40 | 1.27 | 0.016 | 0.050 | | |
| М | 0 ° | 8 ° | 0 ° | 8 ° | | |
| Ν | 0.25 | 0.50 | 0.010 | 0.020 | | |
| S | 5.80 | 6.20 | 0.228 | 0.244 | | |

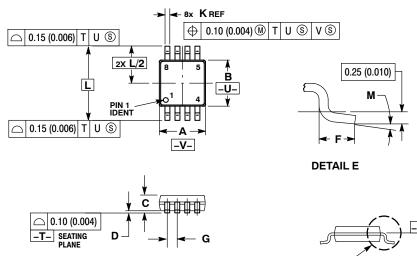
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-8 CASE 948R-02 ISSUE A



| DETAIL E | |
|----------|--|
|----------|--|

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH. OR GATE BURRS SHALL NOT EXCEED 0.15 (0.069) EED EIDE
- OLOBÓ PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- 5. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 2.90 | 3.10 | 0.114 | 0.122 |
| В | 2.90 | 3.10 | 0.114 | 0.122 |
| С | 0.80 | 1.10 | 0.031 | 0.043 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.40 | 0.70 | 0.016 | 0.028 |
| G | 0.65 BSC | | 0.026 BSC | |
| Κ | 0.25 | 0.40 | 0.010 | 0.016 |
| L | 4.90 BSC | | 0.193 BSC | |
| M | 0° | 6 ° | 0° | 6 ° |

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